

**8-Bit Transceiver****Features**

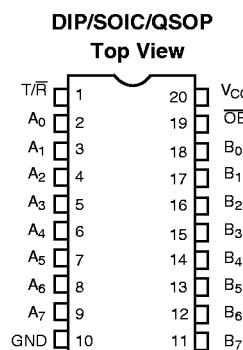
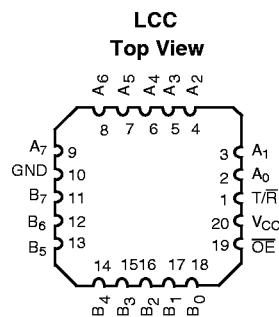
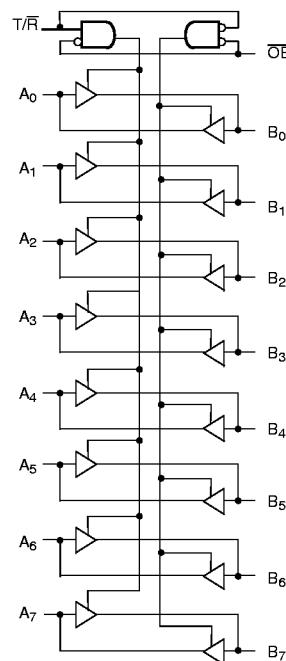
- Function, pinout, and drive compatible with FCT, and F logic
- FCT-D speed at 3.8 ns max. (Com'l), FCT-C speed at 4.1 ns max. (Com'l), FCT-A speed at 4.6 ns max. (Com'l)
- Reduced  $V_{OH}$  (typically = 3.3V) versions of equivalent FCT functions
- Edge-rate control circuitry for significantly improved noise characteristics
- Power-off disable feature
- ESD > 2000V
- Matched rise and fall times
- Fully compatible with TTL input and output logic levels
- Extended commercial range of -40°C to +85°C
- Sink current 64 mA (Com'l), 48 mA (Mil)  
Source current 32 mA (Com'l), 12 mA (Mil)

**Functional Description**

The FCT245T contains eight non-inverting bidirectional buffers with three-state outputs and is intended for bus oriented applications. For the FCT245T, current sinking capability is 64 mA at the A and B ports.

The Transmit/Receiver ( $T/R$ ) input determines the direction of data flow through bidirectional transceiver. Transmit (Active HIGH) enables data from A ports to B ports. The output enable ( $\overline{OE}$ ), when HIGH, disables both the A and B ports by putting them in a High Z condition.

The outputs are designed with a power-off disable feature to allow for live insertion of boards.

**Logic Block Diagram****Pin Configurations****Function Table<sup>[1]</sup>**

$\overline{OE}$	$T/R$	Operation
L	L	B Data to Bus A
L	H	A Data to Bus B
H	X	High Z State

**Note:**

1. H = HIGH Voltage Level. L = LOW Voltage Level. X = Don't Care.

### Maximum Ratings<sup>[2,3]</sup>

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature ..... -65°C to +150°C

Ambient Temperature with

Power Applied ..... -65°C to +135°C

Supply Voltage to Ground Potential ..... -0.5V to +7.0V

DC Input Voltage ..... -0.5V to +7.0V

DC Output Voltage ..... -0.5V to +7.0V

DC Output Current (Maximum Sink Current/Pin) ..... 120 mA

Power Dissipation .....	0.5W
Static Discharge Voltage.....	>2001V
(per MIL-STD-883, Method 3015)	

### Operating Range

Range	Range	Ambient Temperature	V <sub>CC</sub>
Commercial	DT	0°C to +70°C	5V ± 5%
Commercial	T, AT, CT	-40°C to +85°C	5V ± 5%
Military <sup>[4]</sup>	All	-55°C to +125°C	5V ± 10%

### Electrical Characteristics Over the Operating Range

Parameter	Description	Test Conditions		Min.	Typ. <sup>[5]</sup>	Max.	Unit
V <sub>OH</sub>	Output HIGH Voltage	V <sub>CC</sub> =Min., I <sub>OH</sub> =-32 mA	Com'l	2.0			V
		V <sub>CC</sub> =Min., I <sub>OH</sub> =-15 mA	Com'l	2.4	3.3		V
		V <sub>CC</sub> =Min., I <sub>OH</sub> =-12 mA	Mil	2.4	3.3		V
V <sub>OL</sub>	Output LOW Voltage	V <sub>CC</sub> =Min., I <sub>OL</sub> =64 mA	Com'l		0.3	0.55	V
		V <sub>CC</sub> =Min., I <sub>OL</sub> =48mA	Mil		0.3	0.55	V
V <sub>IH</sub>	Input HIGH Voltage			2.0			V
V <sub>IL</sub>	Input LOW Voltage					0.8	V
V <sub>H</sub>	Hysteresis <sup>[6]</sup>	All inputs			0.2		V
V <sub>IK</sub>	Input Clamp Diode Voltage	V <sub>CC</sub> =Min., I <sub>IN</sub> =-18 mA			-0.7	-1.2	V
I <sub>I</sub>	Input HIGH Current	V <sub>CC</sub> =Max., V <sub>IN</sub> =V <sub>CC</sub>				5	µA
I <sub>IH</sub>	Input HIGH Current	V <sub>CC</sub> =Max., V <sub>IN</sub> =2.7V				±1	µA
I <sub>IL</sub>	Input LOW Current	V <sub>CC</sub> =Max., V <sub>IN</sub> =0.5V				±1	µA
I <sub>OS</sub>	Output Short Circuit Current <sup>[7]</sup>	V <sub>CC</sub> =Max., V <sub>OUT</sub> =0.0V		-60	-120	-225	mA
I <sub>OFF</sub>	Power-Off Disable	V <sub>CC</sub> =0V, V <sub>OUT</sub> =4.5V				±1	µA

### Capacitance<sup>[6]</sup>

Parameter	Description	Typ. <sup>[5]</sup>	Max.	Unit
C <sub>IN</sub>	Input Capacitance	5	10	pF
C <sub>OUT</sub>	Output Capacitance	9	12	pF

#### Notes:

2. Unless otherwise noted, these limits are over the operating free-air temperature range.
3. Unused inputs must always be connected to an appropriate logic voltage level, preferably either V<sub>CC</sub> or ground.
4. T<sub>A</sub> is the "instant on" case temperature.
5. Typical values are at V<sub>CC</sub>=5.0V, T<sub>A</sub>=+25°C ambient.
6. This parameter is specified but not tested.
7. Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample and hold techniques are preferable in order to minimize internal chip heating and more accurately reflect operational values. Otherwise prolonged shorting of a high output may raise the chip temperature well above normal and thereby cause invalid readings in other parametric tests. In any sequence of parameter tests, I<sub>OS</sub> tests should be performed last.

## Power Supply Characteristics

Parameter	Description	Test Conditions	Typ. <sup>[5]</sup>	Max.	Unit
I <sub>CC</sub>	Quiescent Power Supply Current	V <sub>CC</sub> =Max., V <sub>IN</sub> ≤0.2V, V <sub>IN</sub> ≥V <sub>CC</sub> -0.2V	0.1	0.2	mA
ΔI <sub>CC</sub>	Quiescent Power Supply Current (TTL inputs HIGH)	V <sub>CC</sub> =Max., V <sub>IN</sub> =3.4V, <sup>[8]</sup> f <sub>1</sub> =0, Outputs Open	0.5	2.0	mA
I <sub>CCD</sub>	Dynamic Power Supply Current <sup>[9]</sup>	V <sub>CC</sub> =Max., One Input Toggling, 50% Duty Cycle, Outputs Open, T/R or OE=GND and V <sub>IN</sub> ≤0.2V or V <sub>IN</sub> ≥V <sub>CC</sub> -0.2V	0.06	0.12	mA/MHz
I <sub>C</sub>	Total Power Supply Current <sup>[10]</sup>	V <sub>CC</sub> =Max., 50% Duty Cycle, Outputs Open, One Bit Toggling at f <sub>1</sub> =10 MHz, T/R or OE=GND and V <sub>IN</sub> ≤0.2V or V <sub>IN</sub> ≥V <sub>CC</sub> -0.2V	0.7	1.4	mA
		V <sub>CC</sub> =Max., 50% Duty Cycle, Outputs Open, One Bit Toggling at f <sub>1</sub> =10 MHz, T/R or OE=GND and V <sub>IN</sub> =3.4V or V <sub>IN</sub> =GND	1.2	3.4	mA
		V <sub>CC</sub> =Max., 50% Duty Cycle, Outputs Open, Eight Bits Toggling at f <sub>1</sub> =2.5 MHz, T/R or OE=GND and V <sub>IN</sub> ≤0.2V or V <sub>IN</sub> ≥V <sub>CC</sub> -0.2V	1.3	2.6 <sup>[11]</sup>	mA
		V <sub>CC</sub> =Max., 50% Duty Cycle, Outputs Open, Eight Bits Toggling at f <sub>1</sub> =2.5 MHz, T/R or OE=GND and V <sub>IN</sub> =3.4V or V <sub>IN</sub> =GND	3.3	10.6 <sup>[11]</sup>	mA

**Notes:**

8. Per TTL driven input (V<sub>IN</sub>=3.4V); all other inputs at V<sub>CC</sub> or GND.
9. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.
10.  $I_C = I_{\text{QUIESCENT}} + I_{\text{INPUTS}} + I_{\text{DYNAMIC}}$   
 $I_C = I_{\text{CC}} + \Delta I_{\text{CC}} D_H N_T + I_{\text{CCD}} (f_0/2 + f_1 N_1)$   
 $I_{\text{CC}} = \text{Quiescent Current with CMOS input levels}$   
 $\Delta I_{\text{CC}} = \text{Power Supply Current for a TTL HIGH input (V}_{\text{IN}}=3.4\text{V)}$   
 $D_H = \text{Duty Cycle for TTL inputs HIGH}$   
 $N_T = \text{Number of TTL inputs at } D_H$   
 $I_{\text{CCD}} = \text{Dynamic Current caused by an input transition pair (HLH or LHL)}$   
 $f_0 = \text{Clock frequency for registered devices, otherwise zero}$   
 $f_1 = \text{Input signal frequency}$   
 $N_1 = \text{Number of inputs changing at } f_1$
- All currents are in millamps and all frequencies are in megahertz.
11. Values for these conditions are examples of the I<sub>CC</sub> formula. These limits are specified but not tested.

**Switching Characteristics** Over the Operating Range

Parameter	Description	FCT245T				FCT245AT				Unit	Fig. No. <sup>[13]</sup>		
		Military		Commercial		Military		Commercial					
		Min. <sup>[12]</sup>	Max.										
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay A to B or B to A	1.5	7.5	1.5	7.0	1.5	4.9	1.5	4.6	ns	1, 3		
t <sub>PZH</sub> t <sub>PZL</sub>	Output Enable Time OE or T/R to A or B	1.5	10.0	1.5	9.5	1.5	6.5	1.5	6.2	ns	1, 7, 8		
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output Disable Time OE or T/R to A or B	1.5	10.0	1.5	7.5	1.5	6.0	1.5	5.0	ns	1, 7, 8		

**Switching Characteristics** Over the Operating Range (continued)

Parameter	Description	FCT245CT				FCT245DT		Unit	Fig. No. <sup>[13]</sup>		
		Military		Commercial		Commercial					
		Min. <sup>[12]</sup>	Max.	Min. <sup>[12]</sup>	Max.	Min. <sup>[12]</sup>	Max.				
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay A to B or B to A	1.5	4.5	1.5	4.1	1.5	3.8	ns	1, 3		
t <sub>PZH</sub> t <sub>PZL</sub>	Output Enable Time OE or T/R to A or B	1.5	6.2	1.5	5.8	1.5	5.0	ns	1, 7, 8		
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output Disable Time OE or T/R to A or B	1.5	5.2	1.5	4.8	1.5	4.3	ns	1, 7, 8		

**Ordering Information**

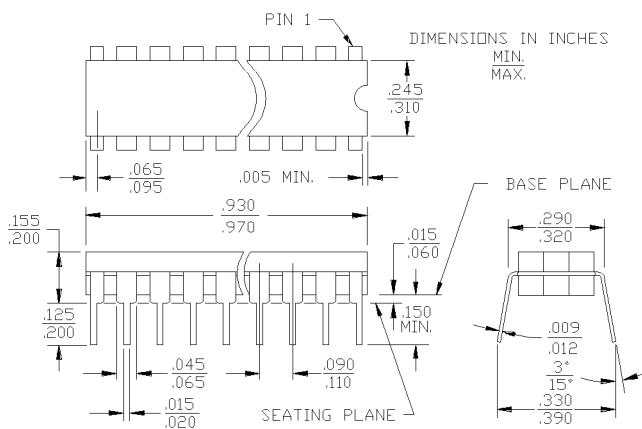
Speed (ns)	Ordering Code	Package Name	Package Type			Operating Range
3.8	CY74FCT245DTQCT	Q5	20-Lead (150-Mil) QSOP			Commercial
	CY74FCT245DTSOC/SOCT	S5	20-Lead (300-Mil) Molded SOIC			
4.1	CY74FCT245CTQCT	Q5	20-Lead (150-Mil) QSOP			Commercial
	CY74FCT245CTSOC/SOCT	S5	20-Lead (300-Mil) Molded SOIC			
4.5	CY54FCT245CTDMB	D6	20-Lead (300-Mil) CerDIP			Military
	CY54FCT245CTLMB	L61	20-Square Leadless Chip Carrier			
4.6	CY74FCT245ATPC	P5	20-Lead (300-Mil) Molded DIP			Commercial
	CY74FCT245ATQCT	Q5	20-Lead (150-Mil) QSOP			
	CY74FCT245ATSOC/SOCT	S5	20-Lead (300-Mil) Molded SOIC			
4.9	CY54FCT245ATDMB	D6	20-Lead (300-Mil) CerDIP			Military
	CY54FCT245ATLMB	L61	20-Square Leadless Chip Carrier			
7.0	CY74FCT245TQCT	Q5	20-Lead (150-Mil) QSOP			Commercial
	CY74FCT245TSOC/SOCT	S5	20-Lead (300-Mil) Molded SOIC			
7.5	CY54FCT245TDMB	D6	20-Lead (300-Mil) CerDIP			Military
	CY54FCT245TLMB	L61	20-Square Leadless Chip Carrier			

**Notes:**

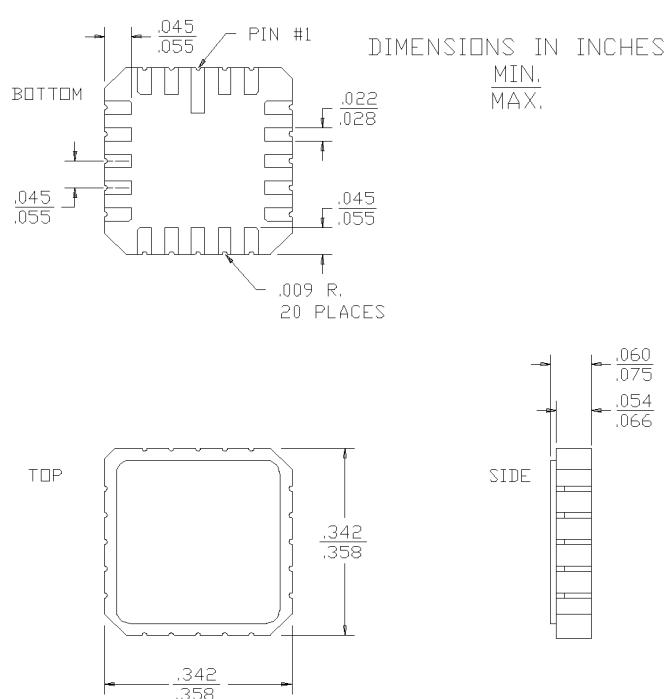
12. Minimum limits are specified but not tested on Propagation Delays.  
 13. See "Parameter Measurement Information" in the General Information section.

## Package Diagrams

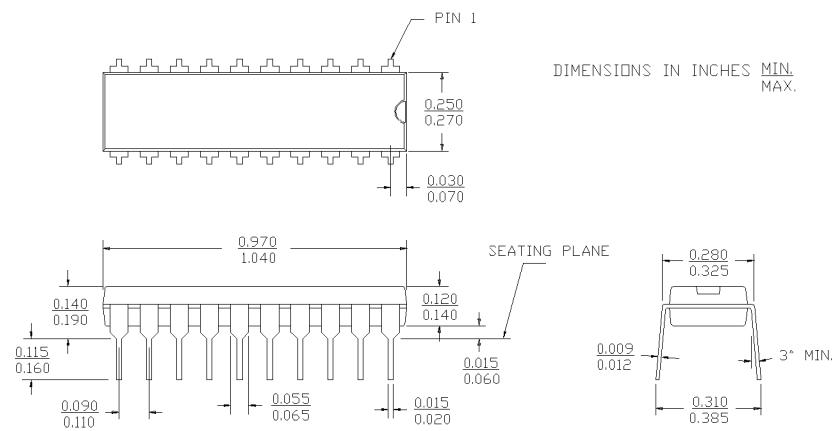
**20-Lead (300-Mil) CerDIP D6**  
MIL-STD-1835 D-8 Config.A

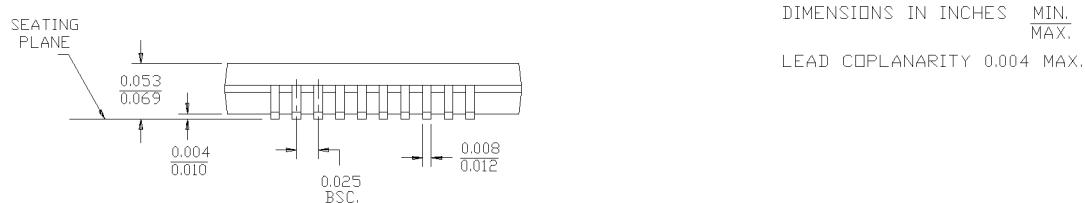
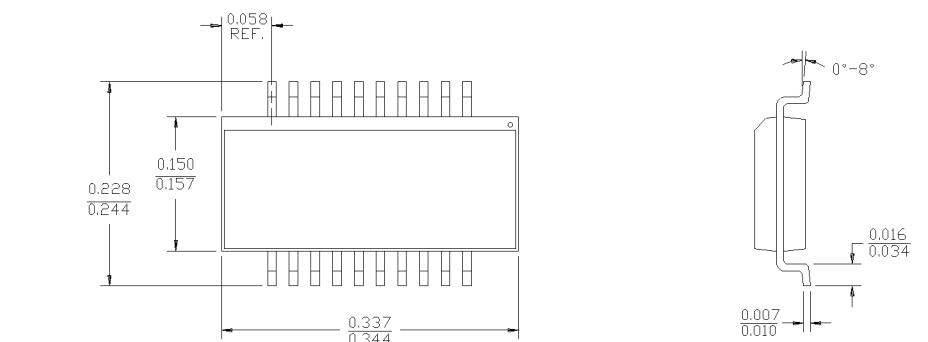


## **20-Pin Square Leadless Chip Carrier L61 MIL-STD-1835 C-2A**



#### **20-Lead (300-Mil) Molded DIP P5**



**Package Diagrams (continued)**
**20-Lead Quarter Size Outline Q5**

**20-Lead (300-Mil) Molded SOIC S5**
